

ANALOG CONTROLLED VARIABLE GAIN AMPLIFIER

Package: MCM, 7mm x7mm



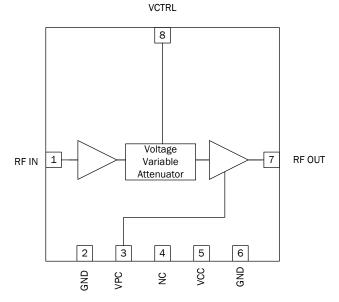


Features

- 2440MHz to 2750MHz Operation
- Gain=28dB Typical
- Gain Adjustment Range > 19 dB
- ACPR=-64dBc Typ. at +12dBm P_{OUT} (Dual Carrier WCDMA)
- Small, 7 mmx7 mm, Multi-Chip Module

Applications

- Cellular, 3G and 4G Infrastructure
- WiBro, WiMax, LTE
- Microwave Radio
- High Linearity Power Control



Functional Block Diagram

Product Description

RFMD's RVA3007L is a fully integrated analog controlled variable gain amplifier featuring exceptional linearity over a greater than 19dB gain control range. This variable gain amplifier is controlled by a single OV to 3.3V positive supply voltage. The RVA3007L is packaged in a small 7 mmx7 mm leadless laminate MCM which contains solid thermal vias for ultra low thermal resistance. This module is internally matched to 50Ω and is easy to use with no external matching components required.

Ordering Information

RVA3007LSQ Sample bag with 25 pieces
RVA3007LSR 7" Sample reel with 100 pieces
RVA3007LTR7 7" Reel with 1500 pieces
RVA3007LTR13 13" Reel with 2500 pieces

RVA3007LPCK-410 2440MHz to 2750MHz PCBA with 5-piece sample bag

Optimum Technology Matching® Applied

☐ GaAs HBT	□ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
☐,GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ RF MEMS
▼ InGaP HBT	☐ SiGe HBT	☐ Si BJT	☐ LDMOS



Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current	770	mA
Max Device Voltage	5.5	V
Max Control Line Voltage	6	V
Max RF Input Power*	12	dBm
Max Junction Temp (T _J)	+150	°C
Max Storage Temp	+150	°C
Thermal Resistance (junction to backside of module)	14.8	°C/W
ESD	Class 1C (1000V min)	
Moisture Sensitivity Level	MSL3	

^{*}Load condition: $Z_L = 50 \Omega$



Caution! ESD sensitive device.

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Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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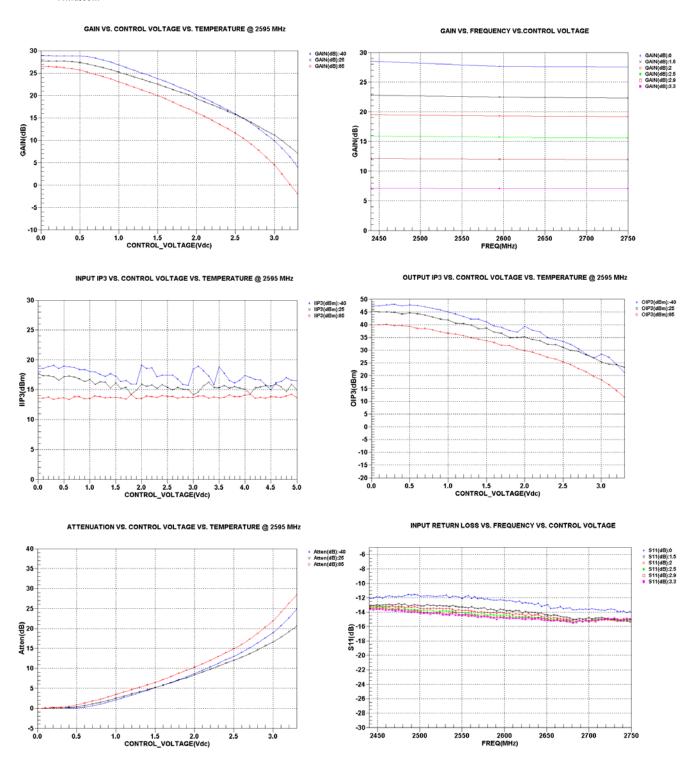
RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter	Specification		Unit	Condition		
Faiailicici	Min.	Min. Typ. Max.		Onit	Condition	
Frequency	2440		2750	MHz		
Temperature Range	-40	25	+85	°C	Operating range	
Gain	25	28	31	dB	Min attenuator setting	
Nominal Operating Output Power		12		dBm	Operating power for ACPR rating	
Output IP3	39	45		dBm	In high gain setting	
P1dB	27	29.5		dBm	High gain setting	
ACPR	-58	-64		dBc	Dual carrier WCDMA, 7.5dB CF at nominal operating power; over full attenuation range	
Gain Flatness		0.2	0.4	dB	Over 50 MHz BW	
Gain Adjustment Range	19			dB		
Control Voltage Range	0		3.3	V		
Noise Figure		5.0	6.5	dB	Min attenuator setting	
Impedance		50		Ω		
Input Return Loss	9	12		dB	Over attenuation range	
Output Return Loss	11	18		dB	Over attenuation range	
Supply Voltage	4.75	5.0	5.25	V		
Supply Current	300	410	550	mA	Max current is at -40°C	
Supply Current (VPC=0V)	65	85	100	mA	Output amplifier shutdown total current; VPC=0V	

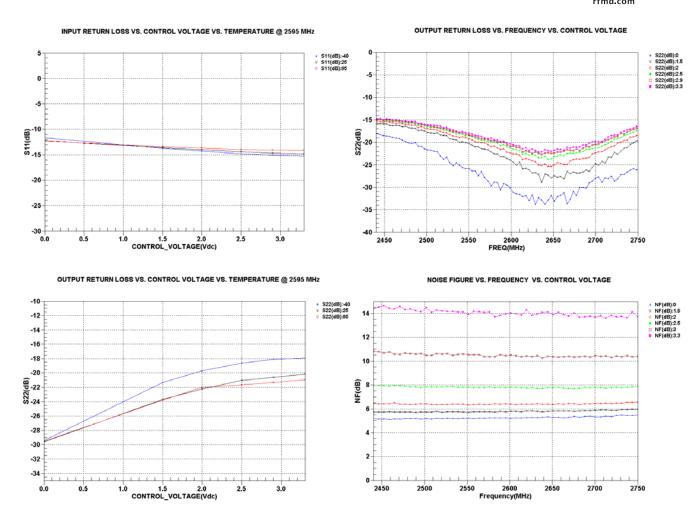






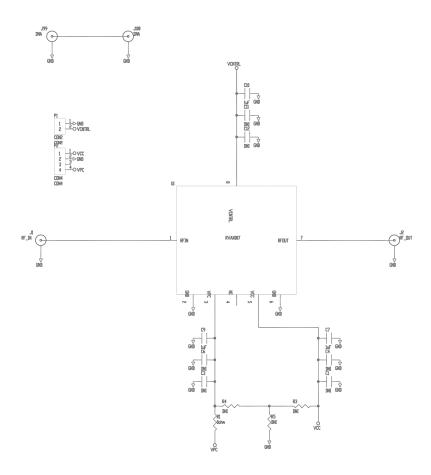








Evaluation Board Schematic



Evaluation Board Bill of Materials (BOM)

Description	Reference	Manufacturer	Manufacturer's P/N
	Designator		
EVALUATION BOARD		DDI	RFVAx007L410(A)
CAP, 1µF, 10%, 10V, X5R, 0402	C7, C9-C10	MURATA ELECTRONICS	GRM155R61A105KE15D
RES, 0Ω, 0402	R1	KAMAYA, INC	RMC1/16SJPTH
CONN, SMA, END LAUNCH, UNIV, HYB MNT, FLT	J1-J2	HEILIND ELECTRONICS	PER MAT-21-1038
CONN, HDR, ST, PLRZD, 4-PIN, 0.100"	P2	ITW PANCON	MPSS100-4-C
CONN, HDR, ST, PLRZD, 2-PIN, 0.100"	P1	ITW PANCON	MPSS100-2-C
DNP	C1, C3-C4, C6, C11-C12, R3-R5		
RVA3007L MODULE	U1	RFMD	RVA3007L



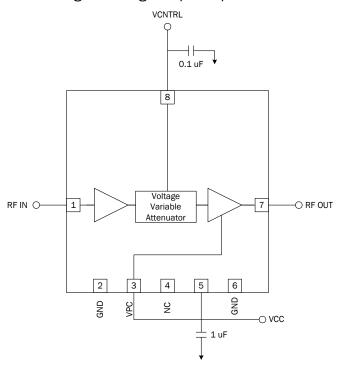
Pin Table and Description

Pin	Function	Description
1	RFIN	RF input pin. Internal DC block.
2	GND	Ground pin.
3	VPC	Power up/down control for 2nd stage amplifier. Apply V_{CC} to power on 2nd stage amplifier. Apply 0V to disable 2nd stage amplifier. Do not exceed $V_{CC}+0.5$ V. Connect to V_{CC} if not needed. Decoupling capacitor may be desired on application board for control line noise.
4	NC	No connection.
5	VCC	Power supply for the module. Recommending 1uF decoupling cap on the application board.
6	GND	Ground pin.
7	RFOUT	RF output pin. Internal DC block.
8	VCTRL	Gain control voltage; 0V to 3.3V range. Maximum gain at 0V. Recommending 0.1uF decoupling on the application board.
Center Pad	GND	Center ground pads need to have a good thermal path on the application board. Use solder stencil pattern shown in the document to define solder paste during assembly.



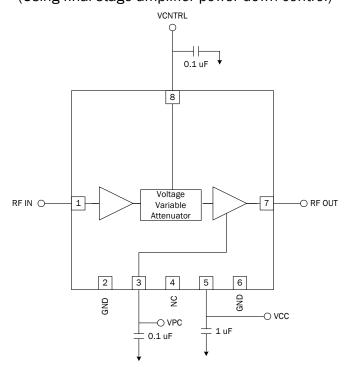
Application Schematic

(Without using final stage amplifier power down control)



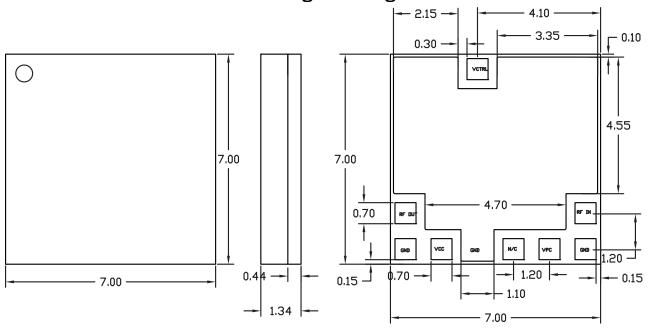
Application Schematic

(Using final stage amplifier power down control)

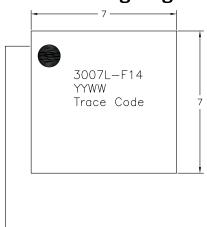




Package Drawing



Branding Diagram



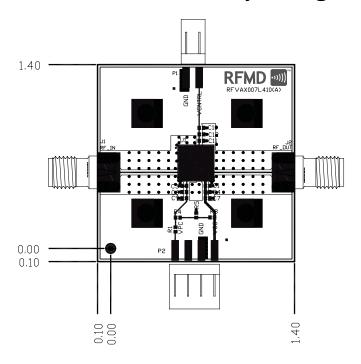
Pin 1 Indicator

Fill in the YYWW Notation with the Date Code YY = Year WW = Week

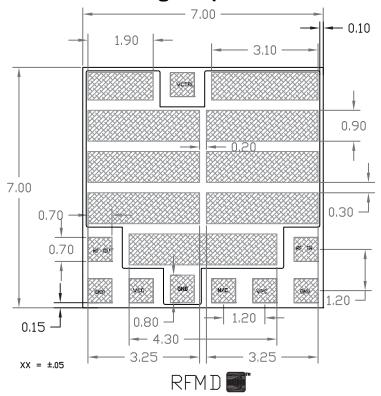
Trace Code to be assigned by SubCon



Evaluation Board Assembly Drawing



PCB Design Requirements



Note: This solder stencil pattern is required to prevent solder voiding that may impact thermal dissipation.